Bulletin I27090 rev. C 05/02

International
IOR Rectifier

IRK. SERIES

STANDARD RECOVERY DIODES **MAGN-A-pak™ Power Modules**

Features

- High voltage
- Electrically isolated base plate
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL E78996 approved

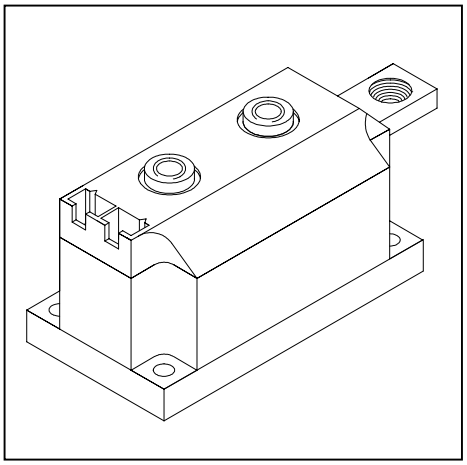
250A
270A
320A

Description

This new IRK series of MAGN-A-paks uses high voltage power diodes in two basic configurations. The semiconductors are electrically isolated from the metal base , allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges and the single diode module can be used in conjunction with the thyristor modules as a freewheel diode. These modules are intended for general purpose applications such as battery chargers, welders and plating equipment and where high voltage and high current are required (motor drives, etc.).

Major Ratings and Characteristics

Parameters		IRK.250..	IRK.270..	IRK.320..	Units
$I_{F(AV)}$		250	270	320	A
	@ T_C	100	100	100	°C
$I_{F(RMS)}$		393	424	502	A
I_{FSM}	@ 50Hz	7015	8920	10110	A
	@ 60Hz	7345	9430	10580	A
I^2t	@ 50Hz	246	398	511	KA^2s
	@ 60Hz	225	363	466	KA^2s
$I^2\sqrt{t}$		2460	3980	5110	$KA^2\sqrt{s}$
V_{RRM}		Up to 2000	Up to 3000	Up to 2000	V
T_J		-40 to 150			°C



ELECTRICAL SPECI ICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , Maximum repetitive peak reverse voltage V	V_{RSM} , Maximum non-repetitive peak reverse voltage V	I_{RRM} Max @ 150°C m A
IRK.250-	04	400	500	50
IRK.270-	08	800	900	
IRK.320-	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
IRK.320-	24	2400	2500	50
	30	3000	3100	

Forward Conduction

	Parameters	IRK.250	IRK.270	IRK.320	Units	Conditions		
$I_{F(AV)}$	Maximum average forward current	250	270	320	A	180° conduction, half sine wave		
	@ Case temperature	100	100	100	°C			
$I_{F(RMS)}$	Maximum RMS forward current	393	424	502	A	as AC switch		
I_{FSM}	Maximum peak, one-cycle forward, non-repetitive surge current	7015	8920	10110	A	t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J$ max
		7345	9340	10580		t = 8.3ms	reapplied	
		5900	7500	8500		t = 10ms	100% V_{RRM}	
		6180	7850	8900		t = 8.3ms	reapplied	
I^2t	Maximum I^2t for fusing	246	398	511	KA^2s	t = 10ms	No voltage	
		225	363	466		t = 8.3ms	reapplied	
		174	281	361		t = 10ms	100% V_{RRM}	
		159	257	330		t = 8.3ms	reapplied	
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	2460	3980	5110	$KA^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied		
$V_{F(TO)1}$	Low level val. of threshold voltage	0.79	0.74	0.69	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{FAV})$, $T_J = T_J$ max.		
$V_{F(TO)2}$	High level val. of threshold voltage	0.92	0.87	0.86	V	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ max.		
r_{t1}	Low level forward slope resistance	0.63	0.94	0.59	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ $T_J = T_J$ max.		
r_{t2}	High level forward slope resistance	0.49	0.81	0.44	mΩ	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ max.		
V_{FM}	Maximum forward voltage drop	1.29	1.48	1.28	V	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = T_J$ max., 180° conduction Av. power = $V_{F(TO)} \times I_{F(AV)} + r_f \times (I_{F(RMS)})^2$		

Blocking

	Parameter	IRK.250/.270/.320	Units	Conditions
I_{RRM}	Max. peak reverse leakage current	50	mA	T_J = 150°C
V_{INS}	RMS isolation voltage	3000	V	50Hz, circuit to base, all terminals shorted, t =1sec

Thermal and Mechanical Specifications

	Parameter	IRK.250 / .270 / .320	Units	Conditions
T_J	Max. junction operating temperature range	-40 to 150	°C	
T_{stg}	Max. storage temperature range	-40 to 150	°C	
R_{thJC}	Max. thermal resistance, junction to case	0.16 0.125 0.125	K/W	Per junction, DC operation
R_{thCS}	Max. thermal resistance, case to heatsink	0.035	K/W	Mounting surface flat, smooth and greased Per module
T	Mounting torque ±10% MAP to heatsink	4 to 6	Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound
	busbar to MAP	8 to 10		
wt	Approximate weight	800 (30)	g (oz)	

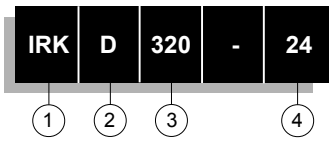
ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sinusoidal conduction @ T_J max.					Rectangular conduction @ T_J max.					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.250-	0.009	0.010	0.014	0.020	0.032	0.007	0.011	0.015	0.021	0.033	K/W
IRK.270-	0.008	0.012	0.014	0.020	0.032	0.007	0.011	0.015	0.020	0.033	
IRK.320-	0.008	0.010	0.013	0.020	0.032	0.007	0.011	0.015	0.020	0.033	

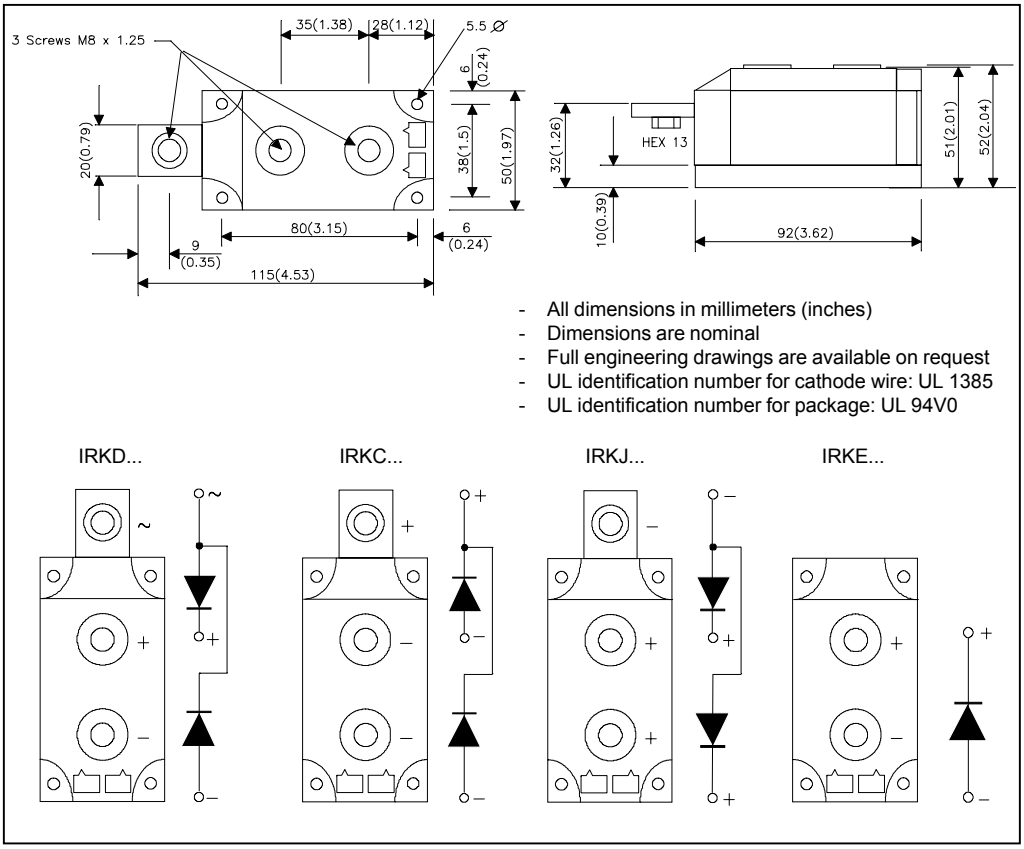
Ordering Information Table

De e Code



1 - Module type
2 - Circuit configuration
3 - Current rating: $I_{F(AV)}$ x 10 rounded
4 - Voltage code: Code x 100 = V_{RRM} (see Voltage Rating Table)

Outline Table



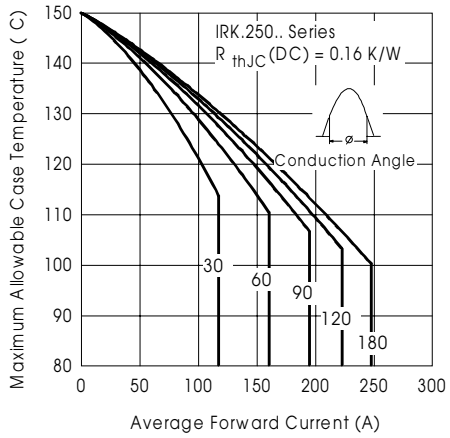


Fig. 1 - Current Ratings Characteristics

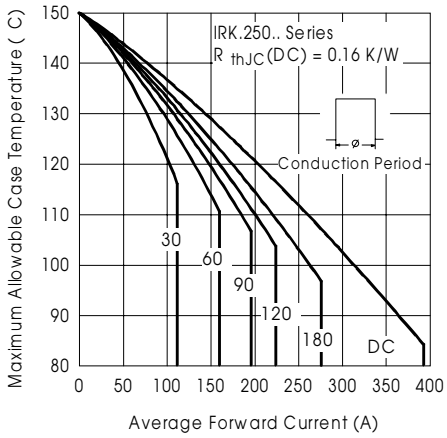


Fig. 2 - Current Ratings Characteristics

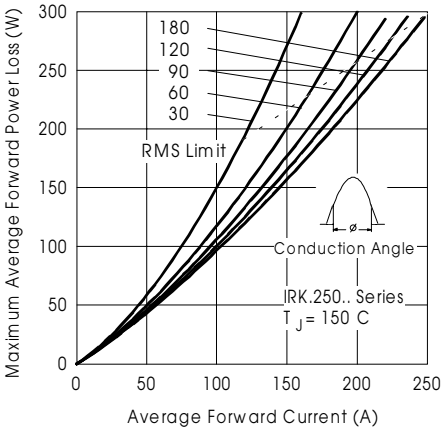


Fig. 3 - Forward Power Loss Characteristics

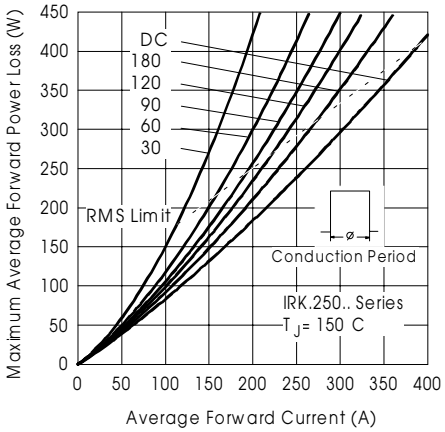


Fig. 4 - Forward Power Loss Characteristics

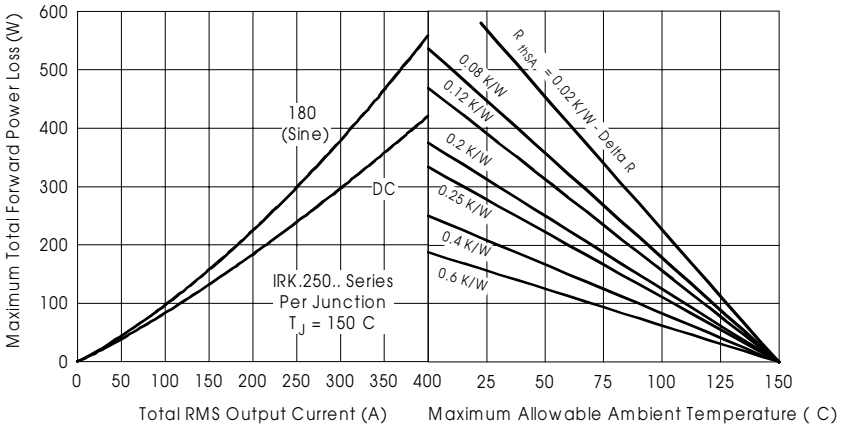


Fig. 5 - Forward Power Loss Characteristics

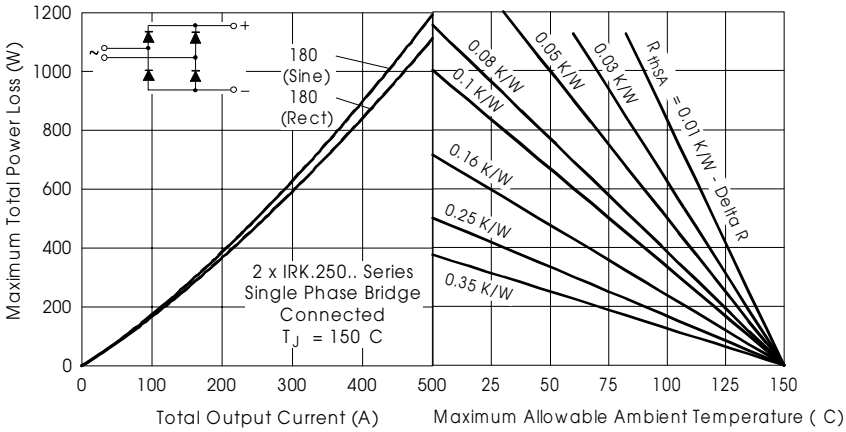


Fig. 6 - Forward Power Loss Characteristics

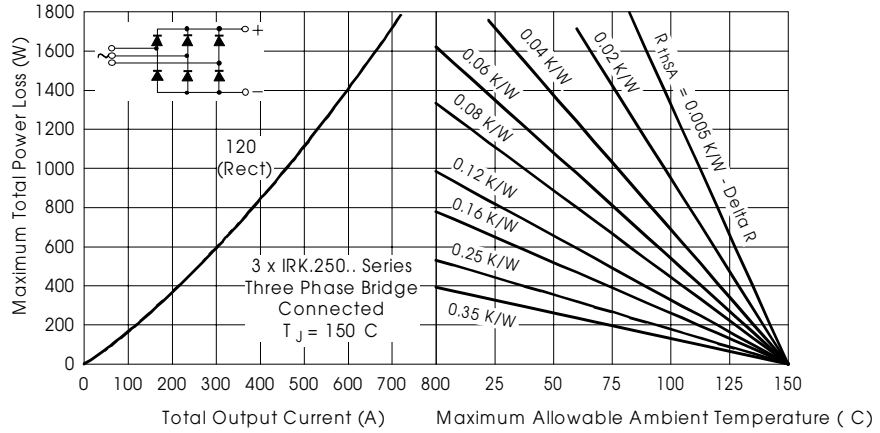


Fig. 7 - Forward Power Loss Characteristics

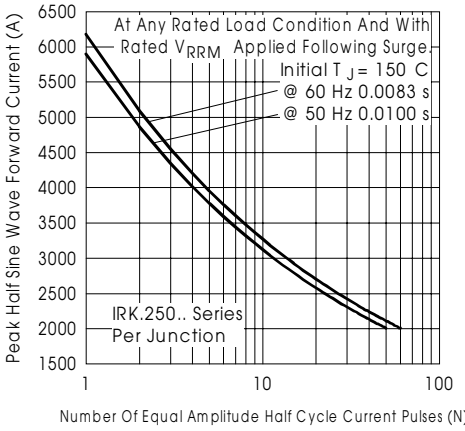


Fig. 8 - Maximum Non-Repetitive Surge Current

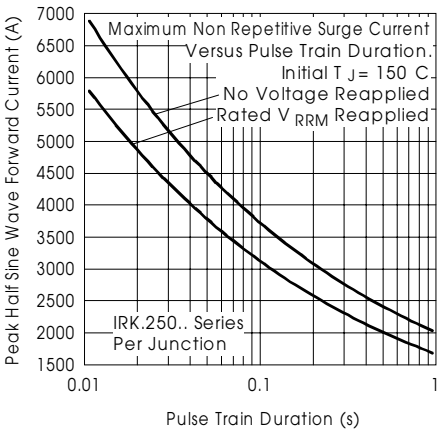


Fig. 9 - Maximum Non-Repetitive Surge Current

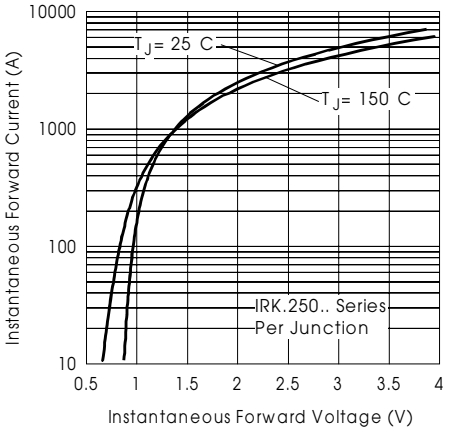


Fig. 10 - Forward Voltage Drop Characteristics

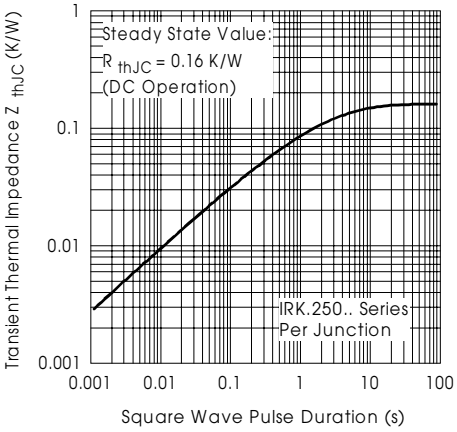


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

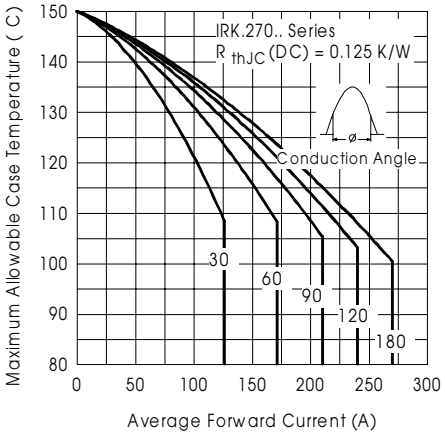


Fig. 12 - Current Ratings Characteristics

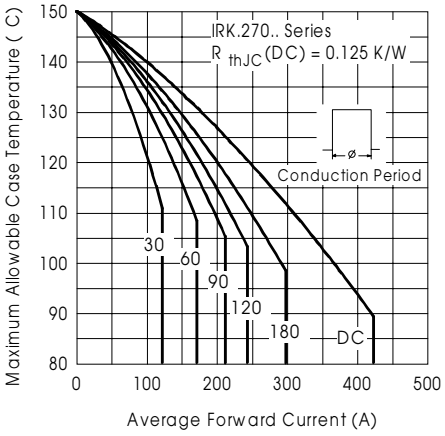


Fig. 13 - Current Ratings Characteristics

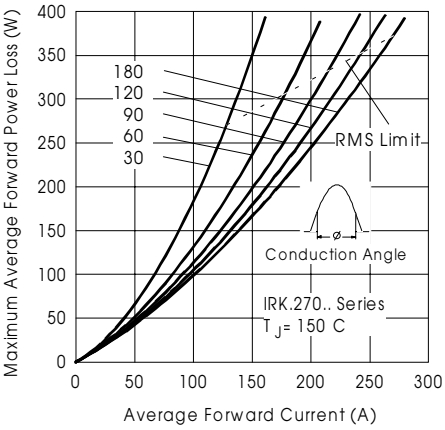


Fig. 14 - Forward Power Loss Characteristics

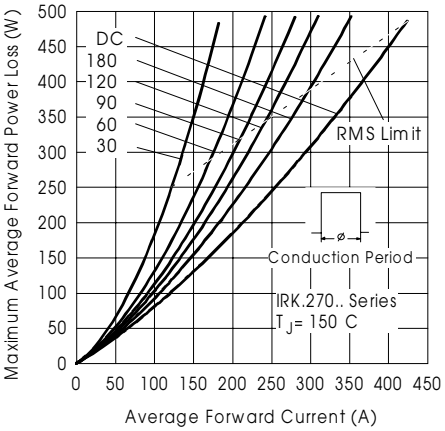


Fig. 15 - Forward Power Loss Characteristics

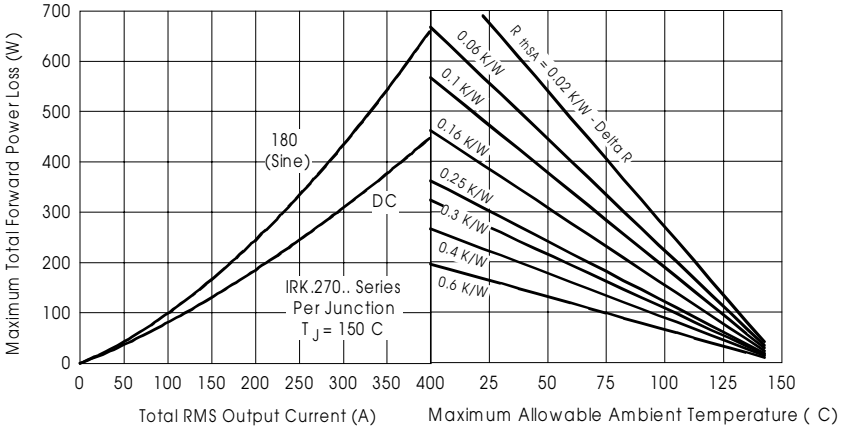


Fig. 16 - Forward Power Loss Characteristics

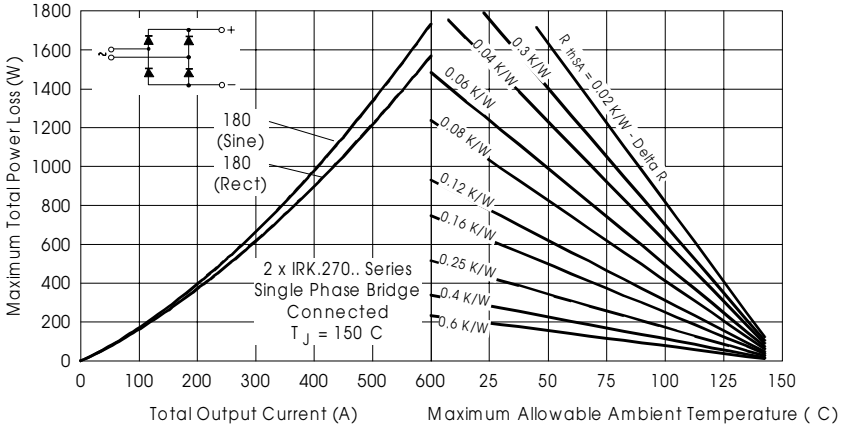


Fig. 17 - Forward Power Loss Characteristics

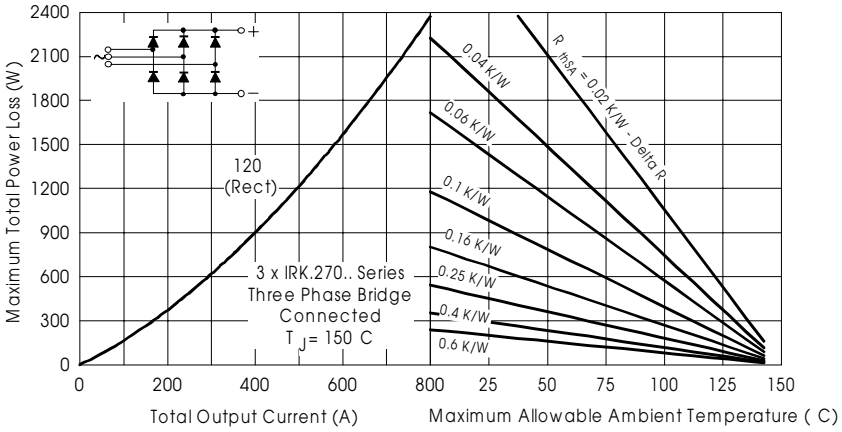


Fig. 18 - Forward Power Loss Characteristics

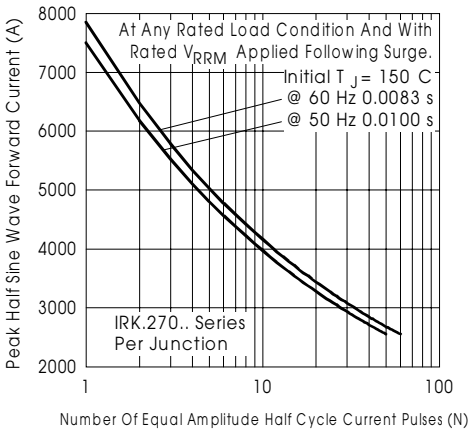


Fig. 19 - Maximum Non-Repetitive Surge Current

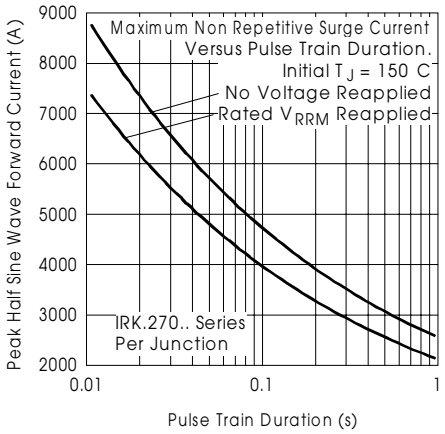


Fig. 20 - Maximum Non-Repetitive Surge Current

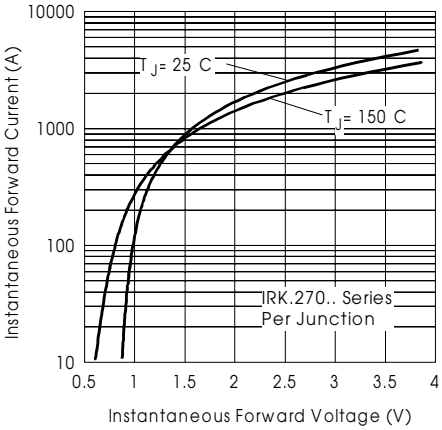


Fig. 21 - Forward Voltage Drop Characteristics

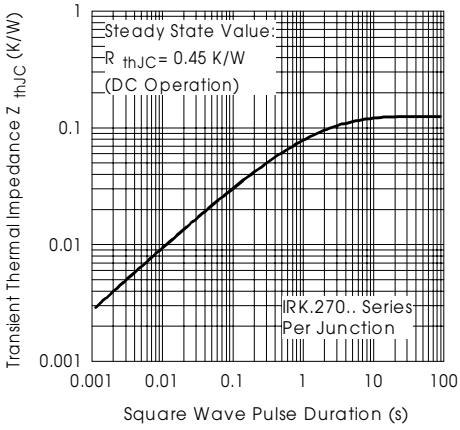


Fig. 22 - Thermal Impedance Z_{thJC} Characteristics

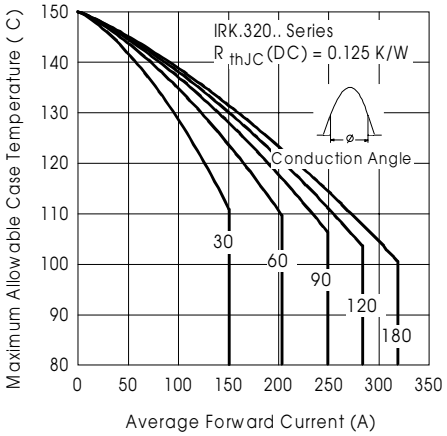


Fig. 23 - Current Ratings Characteristics

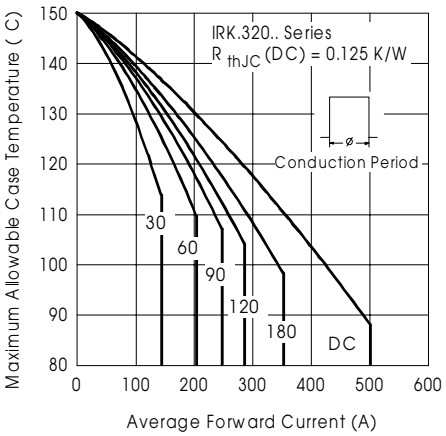


Fig. 24 - Current Ratings Characteristics

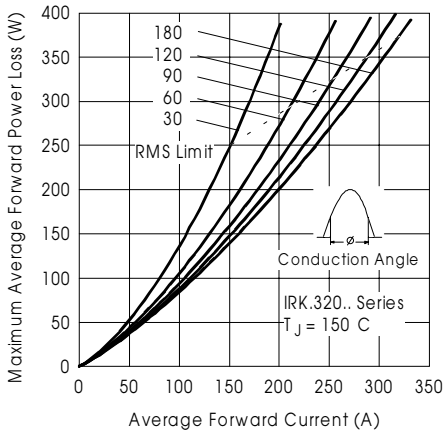


Fig. 25 - Forward Power Loss Characteristics

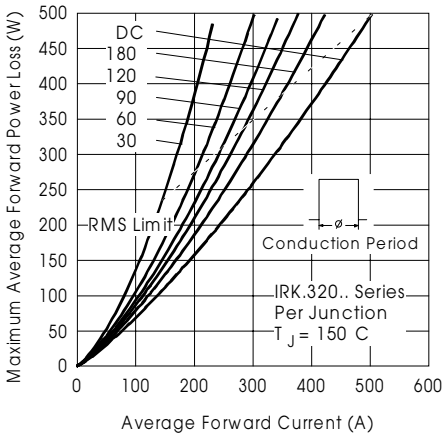


Fig. 26 - Forward Power Loss Characteristics

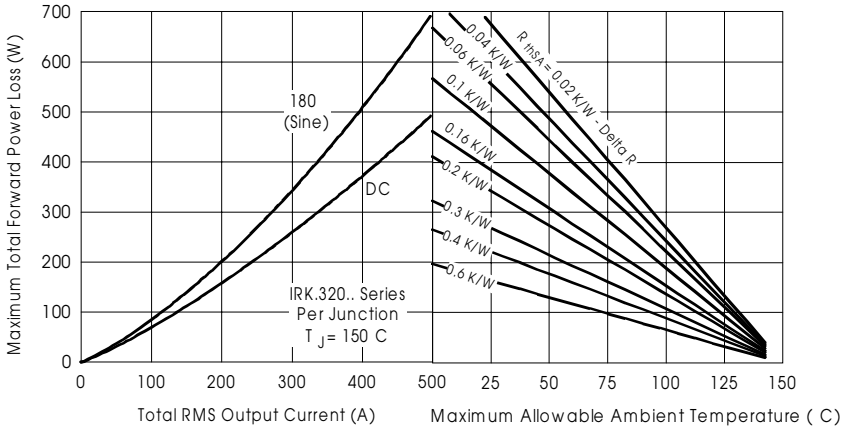


Fig. 27 - Forward Power Loss Characteristics

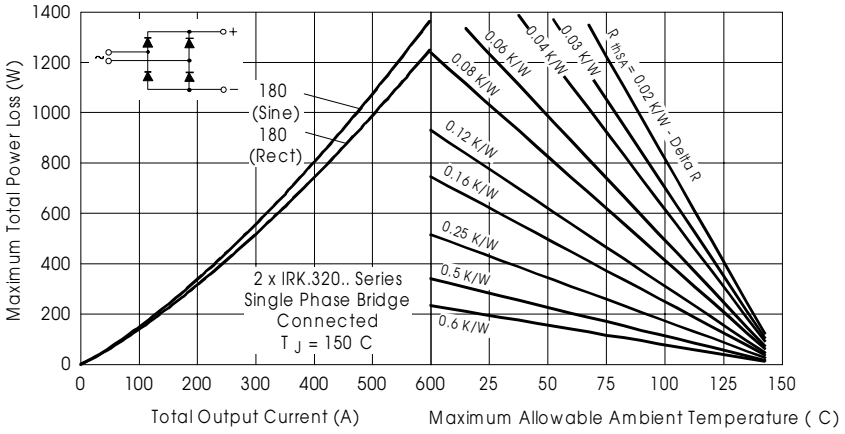


Fig. 28 - Forward Power Loss Characteristics

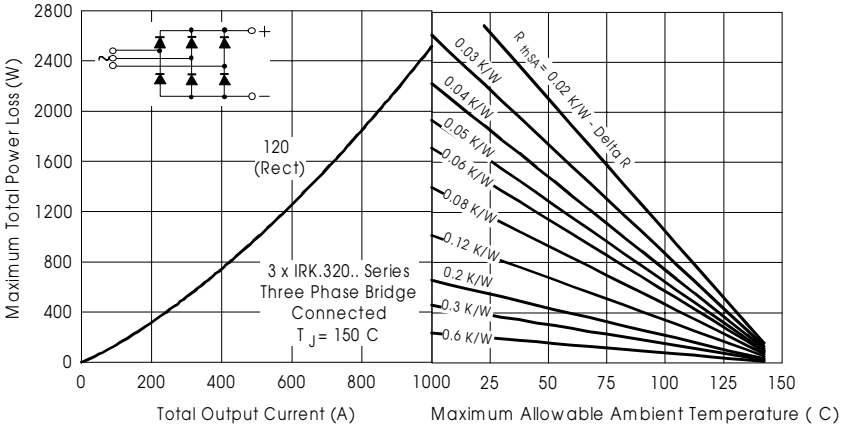


Fig. 29 - Forward Power Loss Characteristics

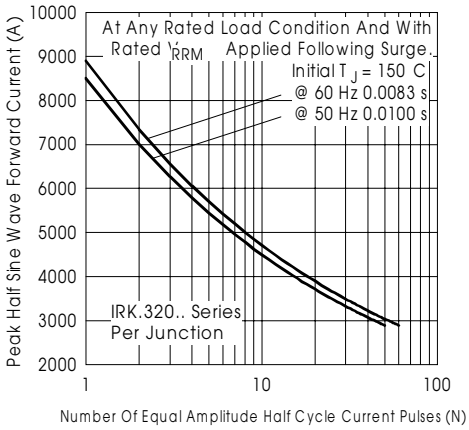


Fig. 30 - Maximum Non-Repetitive Surge Current

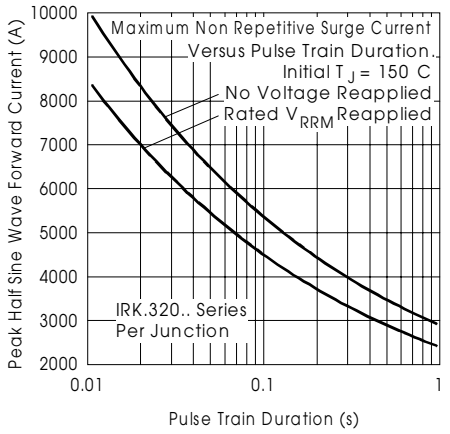


Fig. 31 - Maximum Non-Repetitive Surge Current

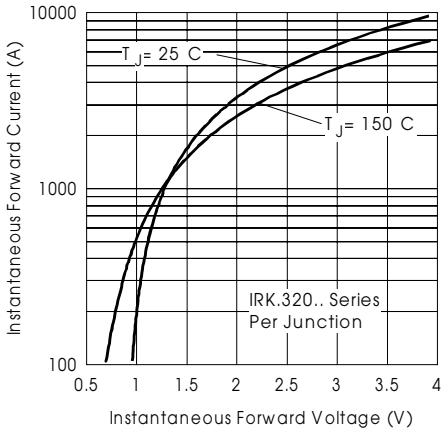


Fig. 32 - Forward Voltage Drop Characteristics

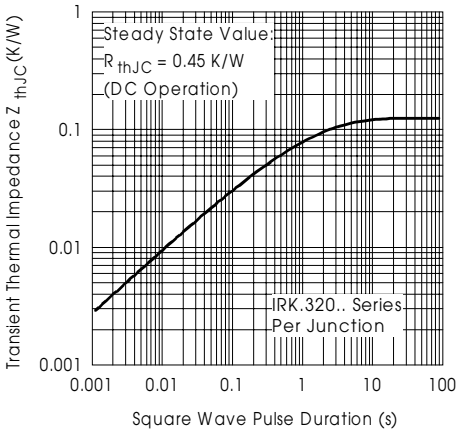


Fig. 33 - Thermal Impedeance Z_{thJC} Characteristics

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

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